

Features

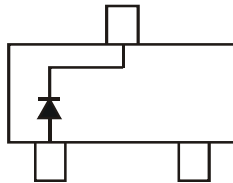
- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- Ultra-Small Surface Mount Package
- **Lead Free/RoHS Compliant (Note 3)**
- **"Green" Device (Note 4 and 5)**

Mechanical Data

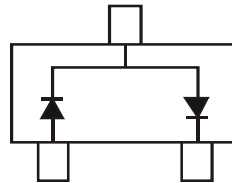
- Case: SOT-523
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish - Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Polarity: See Diagrams Below
- Marking Information: See Page 2
- Ordering Information, See Page 2
- Weight: 0.002 grams (approximate)



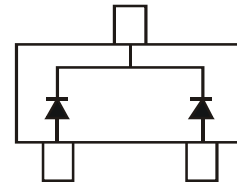
Top View



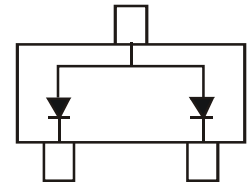
BAS70T



BAS70-04T



BAS70-05T



BAS70-06T

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	70	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{R(RMS)}	49	V
Forward Continuous Current (Note 1)	I _{FM}	70	mA
Non-Repetitive Peak Forward Surge Current @ t _p < 1.0s	I _{FSM}	100	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 1)	P _D	150	mW
Thermal Resistance Junction to Ambient Air (Note 1)	R _{θJA}	833	°C/W
Operating Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	V _{(BR)R}	70	—	—	I _R = 10μA
Forward Voltage	V _F	—	410 1000	mV	t _p < 300μs, I _F = 1.0mA t _p < 300μs, I _F = 15mA
Leakage Current (Note 2)	I _R	—	100	nA	t _p < 300μs, V _R = 50V
Total Capacitance	C _T	—	2.0	pF	V _R = 0V, f = 1.0MHz
Reverse Recovery Time	t _{rr}	—	5.0	ns	I _F = I _R = 10mA to I _R = 1.0mA, I _{rr} = 0.1 x I _R , R _L = 100Ω

- Notes:
1. Device mounted on FR-4 PC board with recommended pad layout, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 2. Short duration pulse test used to minimize self-heating effect.
 3. No purposefully added lead.
 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

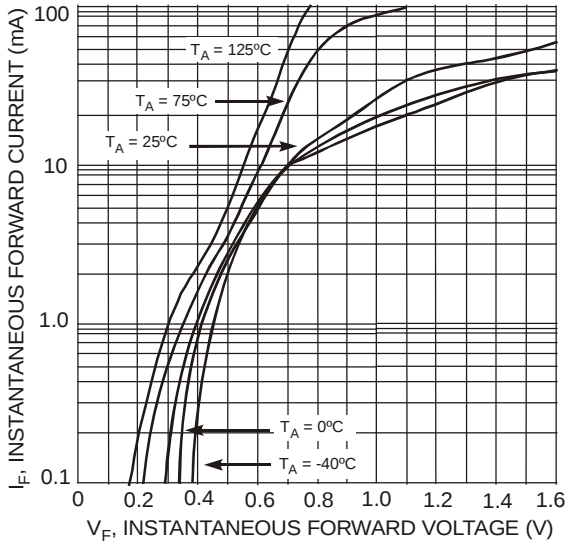


Fig. 1 Typical Forward Characteristics

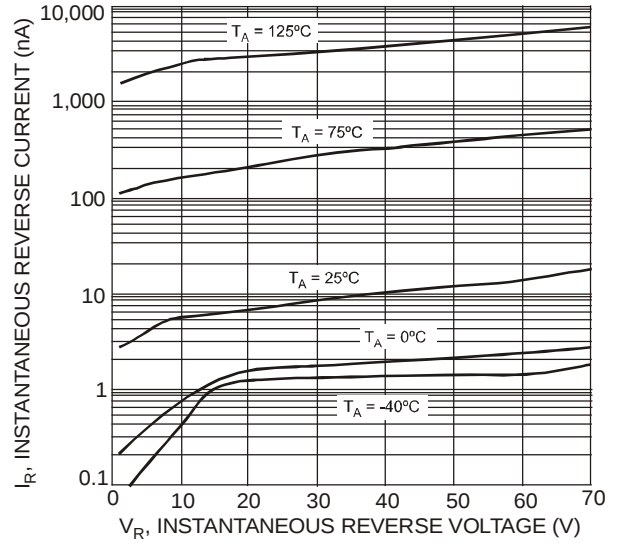


Fig. 2 Typical Reverse Characteristics

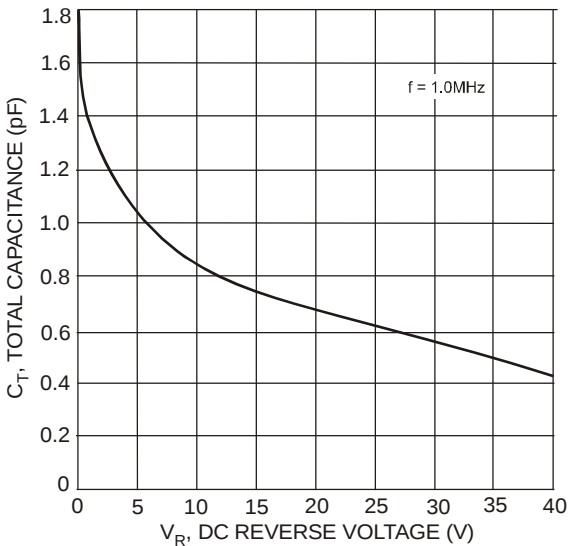


Fig. 3 Total Capacitance vs. Reverse Voltage

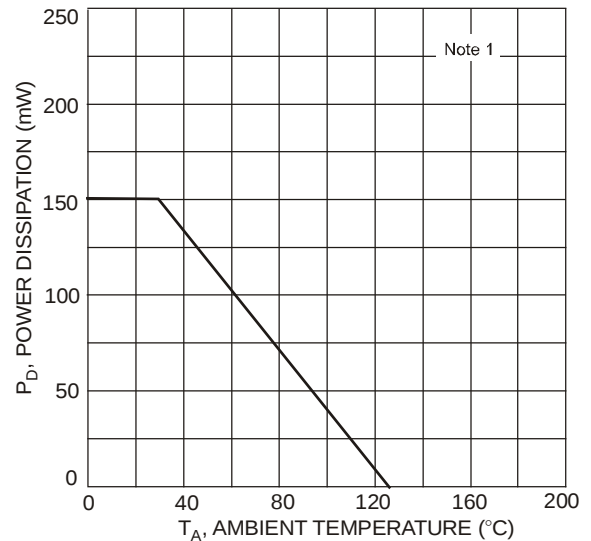


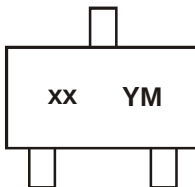
Fig. 4 Power Derating Curve, Total Package

Ordering Information (Note 6)

Part Number	Case	Packaging
BAS70T-7-F	SOT-523	3000/Tape & Reel
BAS70-04T-7-F	SOT-523	3000/Tape & Reel
BAS70-05T-7-F	SOT-523	3000/Tape & Reel
BAS70-06T-7-F	SOT-523	3000/Tape & Reel

 Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



xx = Product Type Marking Code

7C = BAS70T

7D = BAS70-04T

7E = BAS70-05T

7F = BAS70-06T

YM = Date Code Marking

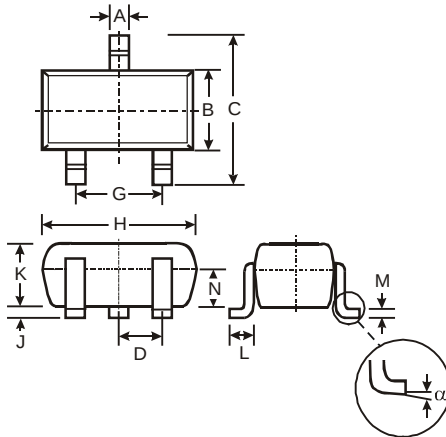
Y = Year (ex: N = 2002)

M = Month (ex: 9 = September)

Date Code Key

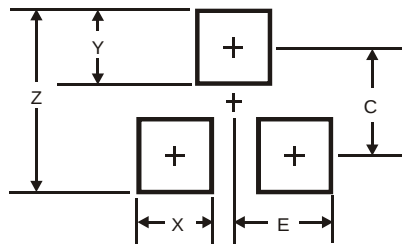
Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code	N	P	R	S	T	U	V	W	X	Y	Z	A	B	C
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec		
Code	1	2	3	4	5	6	7	8	9	O	N	D		

Package Outline Dimensions



SOT-523			
Dim	Min	Max	Typ
A	0.15	0.30	0.22
B	0.75	0.85	0.80
C	1.45	1.75	1.60
D	—	—	0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
J	0.00	0.10	0.05
K	0.60	0.80	0.75
L	0.10	0.30	0.22
M	0.10	0.20	0.12
N	0.45	0.65	0.50
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.8
X	0.4
Y	0.51
C	1.3
E	0.7

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

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